COMPLIANT HALOGEN

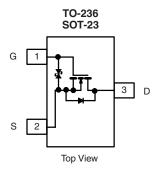
FREE





N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}$ (Ω)	I _D (mA)				
60	2 at V _{GS} = 10 V	300				



2N7002K (7K)*
* Marking Code

Ordering Information: 2N7002K-T1

2N7002K-T1-E3 (Lead (Pb)-free)

2N7002K-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Low On-Resistance: 2 Ω
- · Low Threshold: 2 V (typ.)
- Low Input Capacitance: 25 pF
- · Fast Switching Speed: 25 ns
- Low Input and Output Leakage
- TrenchFET® Power MOSFET
- 2000 V ESD Protection
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- · Low Offset Voltage
- Low-Voltage Operation
- · Easily Driven Without Buffer
- · High-Speed Circuits
- Low Error Voltage

APPLICATIONS

- · Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted									
Parameter		Symbol	Limit	Unit					
Drain-Source Voltage		V_{DS}	60	V					
Gate-Source Voltage		V_{GS}	± 20						
Continuous Drain Current (T _{.I} = 150 °C) ^b	T _A = 25 °C	- I _D	300	mA					
Continuous Drain Current (1 _J = 150 °C)	T _A = 100 °C		190						
Pulsed Drain Current ^a		I _{DM}	800						
Davis Dississification	T _A = 25 °C	P _D	0.35	W					
Power Dissipation ^b	T _A = 100 °C	' D	0.14	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \					
Maximum Junction-to-Ambient ^b		R _{thJA}	350	°C/W					
Operating Junction and Storage Temperature Range		$T_{J_{j}}T_{stg}$	- 55 to 150	°C					

Notes:

- a. Pulse width limited by maximum junction temperature.
- b. Surface Mounted on FR4 board.

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.

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SPECIFICATIONS T _A = 25 °C, unless otherwise noted									
Parameter		Test Conditions	Limits						
	Symbol		Min.	Typ. ^a	Max.	Unit			
Static									
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 10 \mu\text{A}$	60			V			
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1		2.5	•			
Gate-Body Leakage		$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 10	μΑ			
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 15 \text{ V}$			1				
	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 150	nA			
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			± 1000				
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100				
Zero Gate Voltage Drain Current	1	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ			
	I _{DSS}	V_{DS} = 60 V, V_{GS} = 0 V , T_{J} = 125 °C			500				
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 \text{ V}, V_{DS} = 7.5 \text{ V}$	800			mA			
		$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}$	500						
Drain-Source On-Resistance ^a	-	$V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}$			2	Ω			
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			4				
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 200 mA	100			mS			
Diode Forward Voltage	V _{SD}	$I_S = 200 \text{ mA}, V_{GS} = 0 \text{ V}$			1.3	V			
Dynamic ^a			•		•				
Total Gate Charge	Qg	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$ $I_{D} \cong 250 \text{ mA}$		0.4	0.6	nC			
Input Capacitance	C _{iss}			30		pF			
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}$		6					
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		2.5					
Switching ^{a, b, c}					1				
Turn-On Time	t _{d(on)}	$V_{DD} = 30 \text{ V}, R_1 = 150 \Omega$			25	ns			
Turn-Off Time	t _{d(off)}	$I_D \cong 200 \text{ mA}, V_{GEN} = 10 \text{ V}, R_G = 10 \Omega$			35				

Notes:

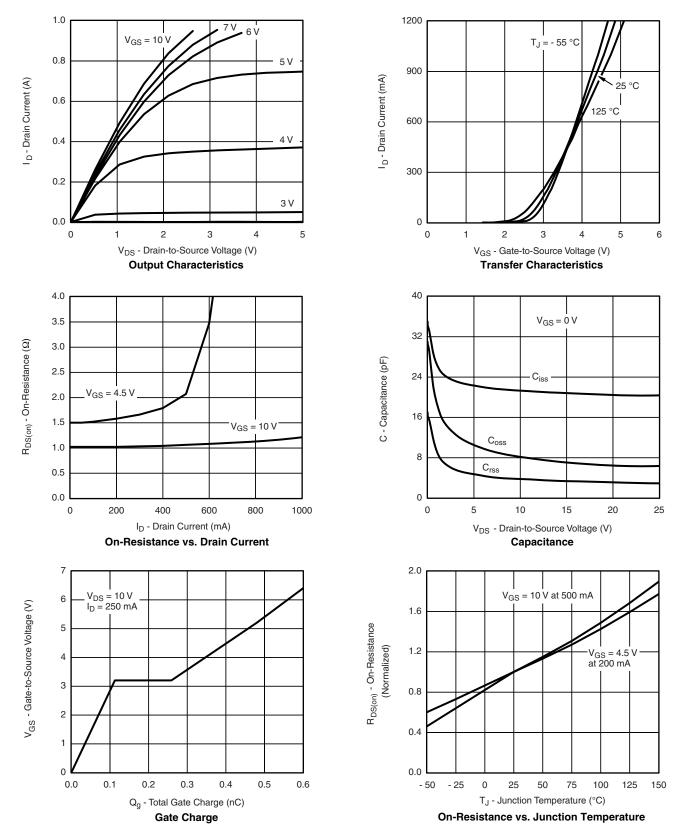
- a. For DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW \leq 300 μ s duty cycle \leq 2 %.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



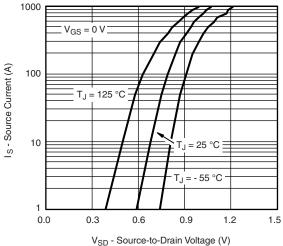


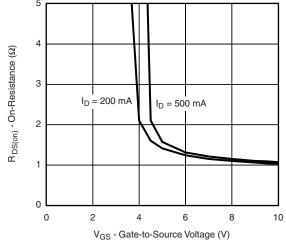
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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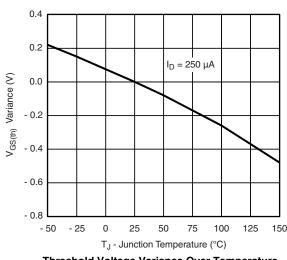
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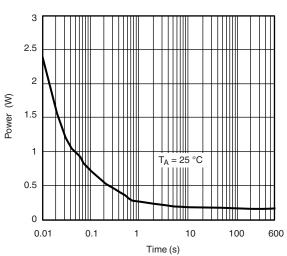




Source-Drain Diode Forward Voltage

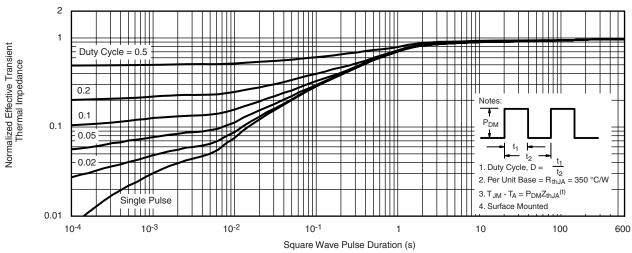
On-Resistance vs. Gate-Source Voltage





Threshold Voltage Variance Over Temperature

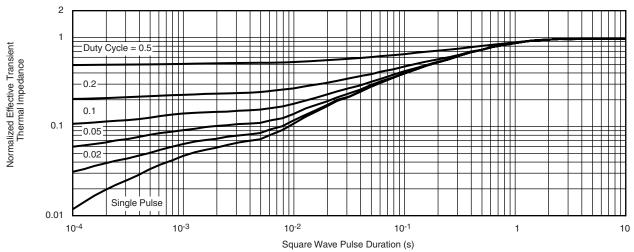
Single Pulse Power, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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